

# LC7152, 7152M, 7152NM, 7152KM

## **Universal Dual-PLL Frequency Synthesizers**



### Overview

The LC7152, 7152M, 7152NM, 7152KM are universal dual-PLL frequency synthesizers for use in weak signal type cordless telephone applications in the USA, South Korea, and Japan, and broadcast satellite (BS) tuners in the USA and Europe.

#### **Features**

- · Dual charge pump built in for fast channel switching
- Digital lock detector enables PLL lock status check with crystal oscillator precision
- Programmable reference frequency divider supports various applications
- The LC7152NM is a built-in power-on reset circuit version of the LC7152M
- The LC7152KM is an enhanced frequency characteristics version of the LC7152M

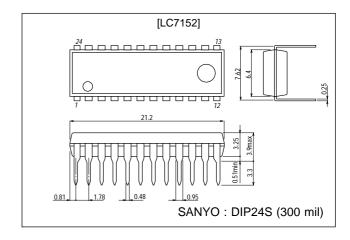
### **Functions**

- 2-system PLL built-in (dual PLL)
- 16-bit programmable local-oscillator divider 1.5 to 55 MHz ( $V_{DD}$  = 2.0 to 3.3 V), LC7152KM: 55 to 80 MHz ( $V_{DD}$  = 2.7 to 3.3 V)
- 14-bit programmable reference-frequency divider
   320 Hz to 640 kHz reference frequency using a 10.24 MHz crystal oscillator
- · Digital lock detector
- · Dual charge pump
- Amplifier built-in for an active LPF
- Serial transmission data input (CCB format)
- LC7152NM with power-on reset circuit (pins OUTA and OUTB become open at power-on)
- 2.0 to 3.3 V supply voltage
- DIP24S and MFP24S packages
  - CCB is a trademark of SANYO ELECTRIC CO., LTD.
     CCB is SANYO's original bus format and all the bus addresses are controlled by SANYO.

# **Package Dimensions**

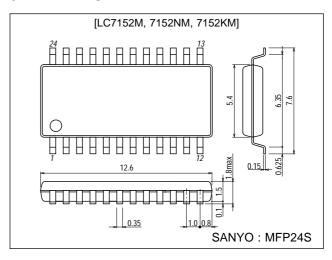
unit: mm

#### 3067-DIP24S



unit: mm

#### 3112-MFP24S



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# **Specifications**

# Absolute Maximum Ratings at $Ta=25^{\circ}C,\,V_{SS}=0~V$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V <sub>DD</sub> max	V <sub>DD</sub>	-0.3 to +7.0	V
Maximum input valtage	V <sub>IN</sub> max(1)	CE, CL, DI, AIA, AIB	-0.3 to +7.0	V
Maximum input voltage	V <sub>IN</sub> max(2)	XIN, PIA, PIB, TEST	-0.3 to V <sub>DD</sub> +0.3	V
	V <sub>O</sub> max(1)	LDI, LDB	-0.3 to +7.0	V
Maximum output voltage	V <sub>O</sub> max(2)	AOA, AOB, OUTA, OUTB	-0.3 to +15	V
waximum output voltage	V <sub>O</sub> max(3)	PDA1, PDA2, PDB1, PDB2, XOUT	-0.3 to V <sub>DD</sub> +0.3	V
Maximum autaut aurrent	I <sub>O</sub> max(1)	LDA, LDB, OUTA, OUTB	0 to 3	mA
Maximum output current	I <sub>O</sub> max(2)	AOA, AOB	0 to 6	mA
		Ta≦85°C, LC7152	350	mW
Allowable power dissipation	Pd max	Ta≦85°C, LC7152M, 7152NM, 7152KM	160	mW
Operating temperature	Topr		-40 to +85	°C
Storage temperature	Tstg		-55 to +125	°C

# Allowable Operating Ranges at Ta = –40 to +85°C, $V_{SS}$ = 0 V

Doromotor	Symbol Conditions —			Unit		
Parameter			min	typ	max	Unit
	V <sub>DD</sub> (1)	$V_{DD}$	2.0		3.3	V
Supply voltage	V <sub>DD</sub> (2)	V <sub>DD</sub> :Serial data retention voltage, see Figure1, *1	1.5			V
Cupply vollage	V <sub>DD</sub> (3)	V <sub>DD</sub> :Power-on reset voltage, t <sub>R</sub> ≧ 20 ms, see Figure1, *1			0.05	V
Input high-level voltage	V <sub>IH</sub> (1)	CE, CL, DI: $V_{DD} = 2.0 \text{ V}$	1.5		5.5	V
Input high-level voltage	V <sub>IH</sub> (2)	CE, CL, DI:V <sub>DD</sub> = 3.3 V	1.7		5.5	V
Input low-level voltage	V <sub>IL</sub> (1)	CE, CL, DI: $V_{DD} = 2.0 \text{ V}$			0.4	V
Input low-level voltage	V <sub>IL</sub> (2)	CE,CL,DI:V <sub>DD</sub> = 3.3 V	0		0.6	V
Output voltage	V <sub>O</sub> (1)	LDA, LDB	0		5.5	V
Output voltage	V <sub>O</sub> (2)	AOA, AOB, OUTA, OUTB	0		13	V
	f <sub>IN</sub> (1)	XIN:Sine wave, capacitively coupled	1.0		13	MHz
Input frequency	f <sub>IN</sub> (2)	PIA, PIB: Sine wave, capacitively coupled *2	1.5		55	MHz
	f <sub>IN</sub> (3)	PIA, PIB: Sine wave, capacitively coupled *3	55		80	MHz
Input amplitude	V <sub>IN</sub> (1)	XIN: Sine wave, capacitively coupled	200		600	mVrms
Input amplitude 	V <sub>IN</sub> (2)	PIA, PIB: Sine wave, capacitively coupled *2,3	100		600	mVrms
Crystal oscillator frequency	f <sub>X'tal</sub>	XIN, XOUT: CI $\leq$ 50 Ω CL $\leq$ 16 pF *4	4	10.24	11	MHz

Note \*1 LC7152NM

	FA/FB (serial data in		it frequency select bits)	\/	Device	
		[0]	[1]	- V <sub>DD</sub>	Device	
*2	f <sub>IN</sub> (2)	1.5 to 23 MHz	20 to 55 MHz	2.0 to 3.3 V	LC7152, 7152M, LC7152NM, 7152KM	
*3	f <sub>IN</sub> (3)		55 to 80 MHz	2.7 to 3.3 V	LC7152KM	

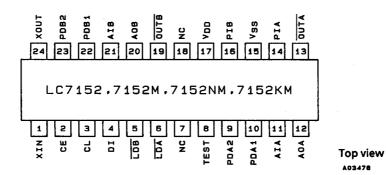
st4 Cl is the crystal impedance and CL is the load capacitance.

## **Electrical Characteristics** in the allowable operating ranges

Parameter	Symbol	Conditions	Rat	tings		Unit
Parameter Symbol		Conditions	min	typ	max	Offic
Output high-level voltage	V <sub>OH</sub> (1)	PDA1, PDB1: I <sub>O</sub> = 1 mA	V <sub>DD</sub> - 1.0			V
Output High-level voltage	V <sub>OH</sub> (2)	PDA2, PDB2: $I_O = 2 \text{ mA}$	V <sub>DD</sub> - 1.0			V
	V <sub>OL</sub> (1)	PDA1, PDB1: I <sub>O</sub> 1 mA			1.0	V
	V <sub>OL</sub> (2)	PDA2, PDB2: $I_O = 2 \text{ mA}$			1.0	V
Output low-level voltage	V <sub>OL</sub> (3)	OUTA, OUTB: I <sub>O</sub> = 1 mA			1.0	V
Output low-level voltage	V <sub>OL</sub> (4)	$\overline{\text{LDA}}$ , $\overline{\text{LDB}}$ : $I_{\text{O}} = 2 \text{ mA}$			1.0	V
	V <sub>OL</sub> (5)	AOA, AOB: $I_O = 0.5$ mA, AIA = AIB = 1.2 V			0.5	V
	V <sub>OL</sub> (6)	AOA, AOB: $I_O = 1$ mA, AIA = AIB = 1.3 V			0.5	٧
	I <sub>OFF</sub> (1)	$\overline{\text{LDA}}$ . $\overline{\text{LDB}}$ : $V_{\text{O}} = 5.5 \text{ V}$			5.0	μA
Output off-leakage current	I <sub>OFF</sub> (2)	PDA1, PDB1, PDA2, PDB2: V <sub>O</sub> = 0/3.3 V		0.01	10.0	nA
	I <sub>OFF</sub> (3)	AOA, AOB, $\overline{\text{OUTA}}$ , $\overline{\text{OUTB}}$ : $V_{\text{O}} = 13 \text{ V}$			5.0	μA
	I <sub>IH</sub> (1)	CE, CL, DI: V <sub>I</sub> = 5.5 V			5.0	μΑ
	I <sub>IH</sub> (2)	$XIN: V_1 = 3.3 V, V_{DD} = 3.3 V$	2.0		6.5	μA
Input high-level current	I <sub>IH</sub> (3)	PIA, PIB: $V_I = 3.3 \text{ V}$ , $V_{DD} = 3.3 \text{ V}$	3.5		10.0	μA
	I <sub>IH</sub> (4)	AIA, AIB: $V_I = 3.3 \text{ V}$		0.01	10.0	nA
	I <sub>IH</sub> (5)	TEST: $V_I = 3.3 \text{ V}, V_{DD} = 3.3 \text{ V}$		120		μΑ
	I <sub>IL</sub> (1)	CE, CL, DI: $V_I = 0 V$			5.0	μΑ
	I <sub>IL</sub> (2)	$XIN: V_{I} = 0 V, V_{DD} = 3.3 V$	2.0		6.5	μΑ
Input low-level current	I <sub>IL</sub> (3)	PIA, PIB: $V_{I} = 0 \text{ V}, V_{DD} = 3.3 \text{ V}$	3.5		10.0	μA
	I <sub>IL</sub> (4)	AIA, AIB: $V_I = 0 V$		0.01	10.0	nΑ
	I <sub>IL</sub> (5)	TEST: $V_{I} = 0 \text{ V}, V_{DD} = 3.3 \text{ V}$			5.0	μA
Internal feedback resistance	R <sub>f</sub> (1)	XIN: V <sub>DD</sub> = 3.3 V		1.0		$\Omega$ M
Internal reedback resistance	R <sub>f</sub> (2)	PIA, PIB:V <sub>DD</sub> = 3.3 V		600		kΩ
Internal pull-down resistance	Rd	TEST: V <sub>DD</sub> = 3.3 V		30		kΩ
Input capacitance C <sub>IN</sub>		XIN, PIA, PIB		2.5		рF
Supply current*1	I <sub>DD</sub> (1)	V <sub>DD</sub> (= 2.0 V):f <sub>IN</sub> = 55 MHz		3.0	8.0	mΑ
	I <sub>DD</sub> (2)	$V_{DD}(= 3.3 \text{ V}):f_{IN} = 55 \text{ MHz}$		7.0	14.0	mΑ
Supply current*2	I <sub>DD</sub> (4)	$V_{DD}(= 2.0 \text{ V}):f_{IN} = 55 \text{ MHz}$		1.5	4.5	mΑ
Supply Culterit 2	I <sub>DD</sub> (5)	$V_{DD}(= 3.3 \text{ V}):f_{IN} = 55 \text{ MHz}$		3.9	8.0	mA

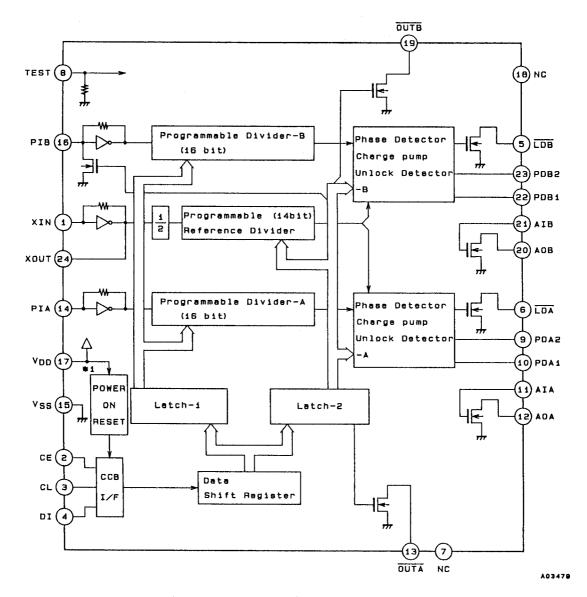
Note \*1. Dual PLL operation (both PLL-A and PLL-B), SB= 0, XIN= 10.24 MHz (crystal), PIA and PIB input = 100 mVrms at  $f_{\text{IN}}$ , all other inputs at  $V_{\text{SS}}$ , all other outputs open.

# **Pin Assignment**



<sup>\*2.</sup> Standby mode: Single PLL operation (PLL-A operating and PLL-B stopped), SB = 1, XIN = 10.24 MHz (crystal), PIA input = 100mVrms at  $f_{IN}$ , all other inputs at  $V_{SS}$ , all other outputs open.

## **Equivalent Block Diagram**



## **Pin Functions**

Symbol	Pin No.	Function		Symbol	Pin No.	Function				
PIB	16	Side-B oscill	ator signal input	PDB2	23	Sub charge pump				
XIN	1	Crustal assil	otor	PDB1	22	Main charge pump				
XOUT	24	Crystal oscil	aloi	AIB	21	Low page filter translators				
PIA	14	Side-A oscill	Side-A oscillator signal output		20	Low-pass filter transistors				
$V_{DD}$	17	Power suppl	Power supply		19	General-purpose output port				
V <sub>SS</sub>	15	Ground	Ground		6	Side-A unlock detection				
CE	2	Carial data	Chip enable	PDA2	9	Sub charge pump				
CL	3	Serial data				input	Clock	PDA1	10	Main charge pump
DI	4		Data	AIA	11	Low page filter transisters				
TEST	8	IC Test		AOA	12	Low-pass filter transistors				
NC	7, 18	No connection	No connections		13	General-purpose output port				
I DB	5	Side-B unloc	k detection			•				

# LC7152, 7152M, 7152NM, 7152KM

# **Pin Description**

Symbol	Pin No.	Function	Description of function					
PIA	14	Side-A local oscillator signal	Side-A programmable divider. The input frequency ranges are as follows.					
		input	FA = [0]	FA = [1]	V <sub>DD</sub>	Device		
			1.5 to 23 MHz	20 to 55 MHz	2.0 to 3.3 V	LC7152, 7152M LC7152NM, 7152KM		
				55 to 80 MHz	2.7 to 3.3 V	LC7152KM		
			FA: Serial data					
			Bits DA0 to DA15	determine the d = 272 to 65535	ivider ratios			
PIB	16	Side-B local-oscillator signal	Side-B programm		, _			
		input	The input frequer	icy ranges are the second		IA.		
			• Bits DB0 to DB15	•				
			Divider ratio N=					
			Serial data: Bit Si     When SR = 1	•		: ndby mode, side-B is		
				pulled down to \		nuby mode, side-b is		
			When SB = 0,	normal operation	is selected.			
XIN	1	Crystal oscillator	Crystal oscillator					
XOUT	24			g a crystal other t stal oscillator mu		d above, its compatibility		
PDA1	10	Side-A main charge pump				ne PLL phase error		
		3.1.1	signals. When the	frequency gene	rated by dividing	g the local oscillator signal		
				•		ency, the charge pump		
			outputs a high-leve			en lower, the charge pump		
						edance.		
PDB1	22	Side-B main charge pump	If the two values match, these pins go to high-impedance.  • fosc/N > fref or leading  → Positive Pulse					
			• fosc/N < fref or → Ne	iagging gative Pulse				
			• fosc/N = fref ar	· ·				
				gh-Impedance				
DDAG		Cide A sub abarga numn	(*SB = [1] : PDB1 -			r signal anly when the		
PDA2	9	Side-A sub charge pump	unlock condition i		PLL phase enoi	r signal only when the		
					set by serial dat	a bits UL0 and UL1.		
PDB2	23	Side-B sub charge pump				tion threshold occurs, this		
			signal goes to hig charge pump is o		d the phase erro	or signal for the main		
					or signal has the	same polarity as the main		
			charge pump.			, , , , , , , , , , , , , , , , , , , ,		
LDA	6	Side-A unlock detector output	Outputs the PLL		3.			
			Locke Unlocke	d: Open				
					lock/unlock disc	crimination is set by serial		
			data bits UL0 and					
LDB	5	Side-B unlock detector output	'''					
			<ul> <li>For details, refer to the description of the serial data.</li> <li>SB = 1: \(\overline{LDB}\) → Open</li> </ul>					
AIA	11	Side-A low-pass filter transistor	MOS N-channel t	•	PLL filter			
AOA	12	,						
AIB	21	Side-B low-pass filter transistor	• The AOA and AO	B output withstar	nd voltage is 13\	V.		
OAB OUTA	20 13	Side-A general purpose	• These latch the s	erial data bite O/	and OR that a	re sent from the controller,		
OUTA	13	Side-A general purpose output port	and then invert a			ie seni nom me connoller,		
OUTB	19	Side-B general purpose	(OUTA can also o	output XIN divided	d by two.			
		output port	In the LC7152NN	, OUTA and OUT	TB are open at t	the power-on reset.		

For more information on crystal oscillator : Nihon Dempa Kogyo Co., Ltd.

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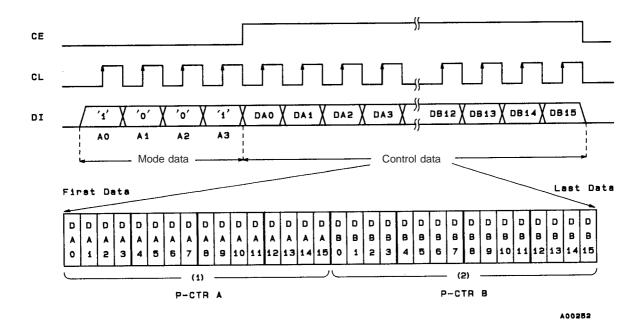
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Symbol	Pin No.	Function	Description of function
CE *1	2	Chip enable input	Set this pin high when inputting serial data to the LC7152.
CL *1	3	Clock input	Clock for data synchronization when inputting serial data to the LC7152.
DI *1	4	Data input	Input for serial data being sent from the controller to the LC7152.
V <sub>DD</sub> V <sub>SS</sub>	17 15	Power supply Ground	LC7152 power supply pin.
TEST	8	IC Test input	LC7152 test pin. (Normally V <sub>SS</sub> or open.)     However, divide-by-two XIN frequency is output from the pin OUTA by applying the V <sub>DD</sub> level voltage after serial data transfer (T0 = T1 = T2 = 0). Crystal oscillation frequency can be checked normally when the pin is left open.

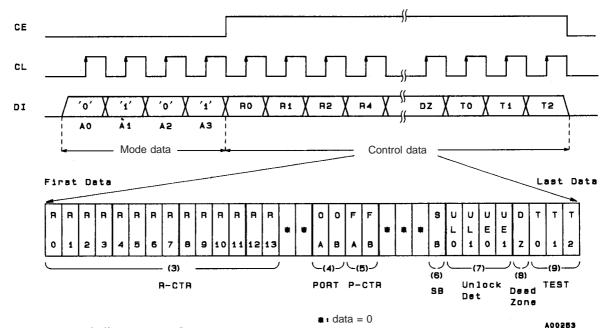
<sup>\*1</sup> The input "H" voltage and the input "L" voltage on the CE, CL, and DI pins are  $V_{IH}=1.5$  to 5.5V and  $V_{IL}=0$  to 0.4V when  $V_{DD}=2.0$ V. When  $V_{DD}=3.3$ V, then  $V_{IH}=1.7$  to 5.5V and  $V_{IL}=0$  to 0.6V. (Voltage greater than  $V_{DD}$  may be applied to  $V_{IH}$ .)

## Serial Input Data (PLL Control data) format

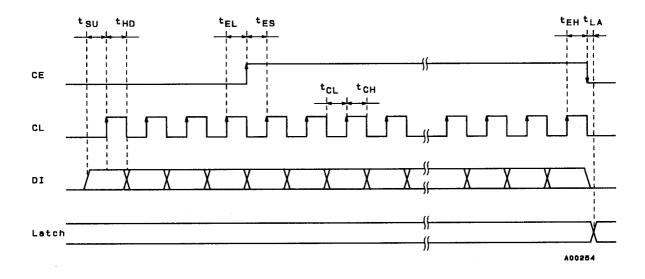
## Mode1: Latch-1 data (programmable divider data)



Mode 2: Latch-2 data (reference divider and control data)



## **Serial Data Transfer Timing**



Symbol	Parameter	10.24 MHz crystal	Other crystal frequencies
t <sub>SU</sub>	Data setup time	At least 0.40 µs	At least 4/f <sub>X'tal</sub>
t <sub>HD</sub>	Data hold time	At least 0.40 µs	At least 4/f <sub>X'tal</sub>
t <sub>EL</sub>	Enable low-level pulse width	At least 0.40µs	At least 4/f <sub>X'tal</sub>
t <sub>ES</sub>	Enable setup time	At least 0.40 µs	At least 4/f <sub>X'tal</sub>
t <sub>EH</sub>	Enable hold time	At least 0.40 µs	At least 4/f <sub>X'tal</sub>
t <sub>CL</sub>	Clock low-level pulse width	At least 0.40 µs	At least 4/f <sub>X'tal</sub>
<sup>t</sup> CH	Clock high-level pulse width	At least 0.40 µs	At least 4/f <sub>X'tal</sub>
t <sub>LA</sub>	Latch propagation delay	Up to 0.40 µs	Up to 4/f <sub>X'tal</sub>

Note Perform data transfer after the crystal oscillations normalize. Data transferred before normal oscillations will not be recognized.

# LC7152, 7152M, 7152NM, 7152KM

# **Description of Serial Data**

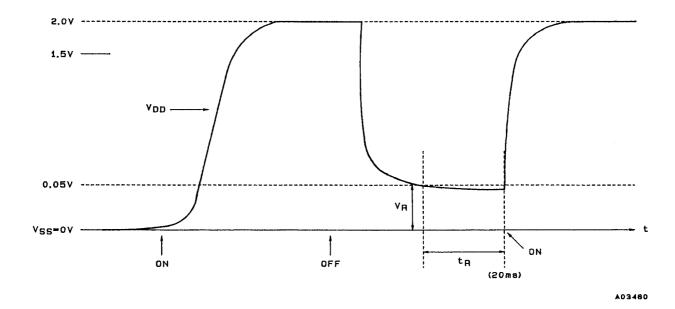
No	Controller/Date				Do	scription				Polotod Data
No. (1)	Controller/Data Side-A	• This dat	a cote	the side-A			ider numbe	r This dat	a ic a	Related Data
(1)	programmable			which DA			idei ildilibe	ii. IIIIS uat	a 13 a	
	divider data: DA0	The rang	ge of o	divider valu			is 272 to 6	5,535.		R0 to R13
	to DA15			O-A/fref						
(2)	Side-B		This data sets the side-B programmable divider number. This data is a							
	programmable	,		which DB			:- 070 +- 0	F F0F		R0 to R13
	divider data: DB0 to DB15		_	divider valu O-B/fref	es that ca	an be set	IS 2/2 to 6	5,535.		
(3)	Reference			the referer	nce divide	r numbe	r This data	is a hinary	value in	
	frequency data: R0	which R								
	to R13	1	•	divider valu				383.		UL0 UI1 UE0 UE1
				divider nun				idar numh	or)	
(4)	Output port data:			frequency rmines the						
(-)	OA, OB		$\rightarrow$ OL		output of	i ilic gen	ciai puipos	c output p	ort.	
		ОВ	$\rightarrow$ OL	JTB						
				Data 1: low		<b>0</b> =				
(5)	lament for some some			wer-on rese						
(5)	Input frequency range switching			ches the inp $B  o PIB$ )	out freque	ency rang	je ior the P	IA and Pie	pins.	
	data: FA, FB	(17,7,7)	,,,,							
			[	Data —		voltage (				DA0 to DA15
				[0]		to 3.3 V to 23 MH				DB0 to DB15
				[0] [1]		to 55 MH				
				ויו	20	10 00 IVII I				
		• In the ca	In the case of the LC7152KM: Data 1: 55 to 80 MHz ( $V_{DD}$ = 2.7 V to 3.3 V)							
(6)	Standby mode data		This data puts the PLL in standby mode.							
	: SB			tandby mod gle PLL op				n B stoppe	d	
						olue-A op	erauriy, side	e-p stoppe	u	
			<ul> <li>SB = 0: standby mode off</li> <li>→ Dual PLL operation: Side-A operating, side-B operating</li> </ul>							
			During the power-on reset in the LC7152NM, SB is "1".							
(7)	Unlock detection			ase error de						
	data	l		scrimination state is dete		resnoia s	SHOWII III UIE	e lable is e	xceeueu,	
								·	init : un	
	: UL0, UL1		П	hase error		2/12/	2/15   75 41   1		unit : µs	
		ULOU		detector		XIN : 1	XIN [MHz]	example		
				threshold	4.0	7.2	8.0	10.24	12.8	
		0 (	0	0	<b></b>	<b>←</b>	<b>←</b>	<b>←</b>	←	
		1 (		±4/f <sub>X'tal</sub>	±1.00	±0.55	±0.50	±0.39	±0.31	
				±16/f <sub>X'tal</sub>	±4.00	±2.22	±2.00	±1.56	±1.20	
		1 1	1 :	±64/f <sub>X'tal</sub>	±16.00	±8.88	±8.00	±6.25	±5.00	
								<b></b>		
			Note the	at if the da	ta change	es in lock	state, the I	PLL will be	unlocked	
			SITIPUL	arny.						
	: UE0, UE1	• The dete	ected i	phase error	(øE) siai	nal can b	e extended	by a certa	in amount	
		of time a	and ou	tput on the	LDA and	I LDB pin	s. This data	a determin	es the	
		length of this extension. However, when UL0 = UL1 = 0, the phase error is								
		not extended, and is output directly.  unit: ms								
		Reference Reference frequency:								
		UE0 UE1 frequency fref [kHz] example								
			-	fref	-	l kHz	5 kHz	12.5 kHz	<u>-</u>	
		0	0	4 × (1/fre	ef)	4.0*	0.8	0.32		
		1	0	8 × (1/fre		8.0	1.6	0.64		
		0	1	32 × (1/fr		32.0	6.4*	2.56		
		1	1	64 × (1/fr	ef)	64.0	12.8	5.12*		
							(*etan	dard value	.)	
							( Starr	aara varac	7	

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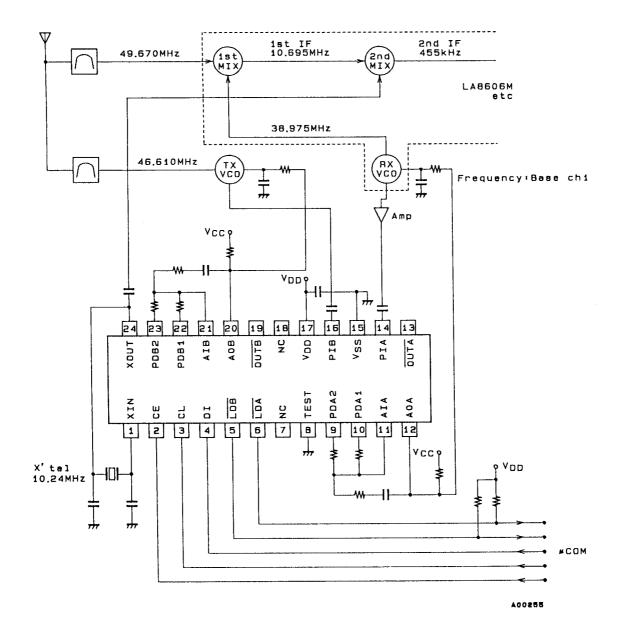
No.	Controller/Data	Description	Related Data
(8)	Dead zone control data: DZ	This data controls the phase comparator dead zone. (DZA < DZB)	
		DZ         Mode           0         DZA           1         DZB	
(9)	IC test data: T0, T1, T2	This is the IC test mode switching data. The user does not need to be concerned about this data.  Assume that T0 = T1 = T2 = 0.  Normally, the test pins must be either at V <sub>SS</sub> or left open.	

# Power-on Reset supply voltage



- Power-on reset is performed when the supply voltage  $V_{DD}$  exceeds 2.0 V by power application after the  $V_{DD}$  has once fallen under 0.05 V and kept the level for at least 20ms.
- $^{\bullet}$  Latch data is retained when the  $V_{DD}$  is 1.5 V, where power-on reset is not performed.

# Sample Application Circuit (FCC: 10 ch 46/49 MHz cordless telephone)



Example: FCC 1-channel 46/49 MHz cordless telephone base station (See diagram in the preceding page.) for fref: 5 kHz, RX VCO: 38.975 MHz, TX VCO: 46.610 MHz

#### **Programmable Divider Data**

(1) 
$$NA = \frac{fVCO - A}{fref} = \frac{RX \ VCO}{fref} = \frac{38.975 MHz}{5kHz} = 7795 \ (DA0 \ to \ DA15)$$

(2) 
$$NB = \frac{fVCO - B}{fref} = \frac{TX \ VCO}{fref} = \frac{46.610 MHz}{5kHz} = 9322 (DB0 \text{ to } DB15)$$
(246A)Hex

(3) Reference frequency data

$$NR = \left(\frac{fX' \text{ tal}}{\text{fref}}\right) \div 2 = \frac{10.24 \text{MHz}}{5 \text{kHz}} \div 2 = 1024 \text{ (R0 to R13)}$$
(400)Hex

(4) Output port data

General-purpose output port: Open (OA = 0, OB = 0)

(5) Input frequency range select bits

$$FA = FB = 1$$

(6) Standby mode

During standby (SB = 1)

(7) Unlock detector output

Extends the phase error signal by 6.4ms if a phase error of  $\pm 6.25$  µs or more is generated.

$$: UL0 = UL1 = 1$$

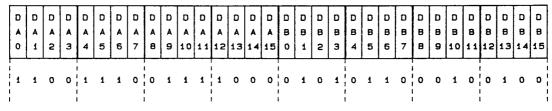
$$: UE0 = 0, UE1 = 1$$

(8) Dead-zone control data

DZA mode : DZ = 0

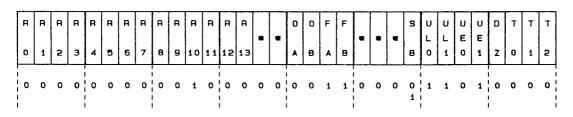
(9) LSI test data: T0 = T1 = T2 = 0

#### (1) Mode 1: Latch-1 data



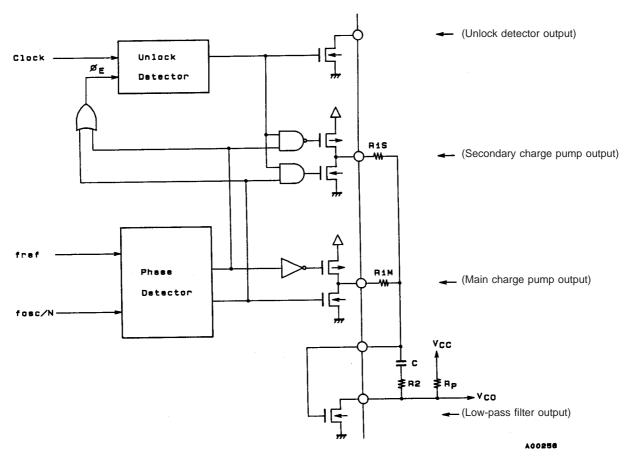
A00256

#### (2) Mode 2: Latch-2 data



A00257

## **Dual Charge Pump Descriptions**



If an unlock state is detected at channel switch, the sub-charge pump operates, R1M/R1S becomes R1, low-pass filter's time constant is reduced, and the lockup accelerates.

When the circuit is locked, side-band characteristics and modulation characteristics are improved by making the sub-charge pump off, i.e., floating, R1M to be R1, and increasing low-pass filter's time constant.

### **Device Comparison**

		Operating frequ	D		
Device	FA/FB = 0	F	A/FB = 1	Power-on reset circuit	Package
	1.5 to 23 MHz	20 to 55 MHz	55 to 80 MHz	Ollodit	
LC7152	Yes	Yes	No	No	DIP24S
LC7152M	Yes	Yes	No	No	MFP24S
LC7152NM	Yes	Yes	No	Yes	MFP24S
LC7152KM	Yes	Yes	Yes (V <sub>DD</sub> = 2.7 to 3.3 V)	No	MFP24S

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